

Chipsmall Limited consists of a professional team with an average of over 10 year of expertise in the distribution of electronic components. Based in Hongkong, we have already established firm and mutual-benefit business relationships with customers from, Europe, America and south Asia, supplying obsolete and hard-to-find components to meet their specific needs.

With the principle of "Quality Parts, Customers Priority, Honest Operation, and Considerate Service", our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip, ALPS, ROHM, Xilinx, Pulse, ON, Everlight and Freescale. Main products comprise IC, Modules, Potentiometer, IC Socket, Relay, Connector. Our parts cover such applications as commercial, industrial, and automotives areas.

We are looking forward to setting up business relationship with you and hope to provide you with the best service and solution. Let us make a better world for our industry!



Contact us

Tel: +86-755-8981 8866 Fax: +86-755-8427 6832

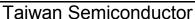
Email & Skype: info@chipsmall.com Web: www.chipsmall.com

Address: A1208, Overseas Decoration Building, #122 Zhenhua RD., Futian, Shenzhen, China











Trench Schottky Rectifier

FEATURES

- Patented Trench Schottky technology
- Excellent high temperature stability
- Low forward voltage
- Low power loss/ high efficiency
- High forward surge capability
- Compliant to RoHS directive 2011/65/EU and in accordance to WEEE 2002/96/EC
- Halogen-free according to IEC 61249-2-21 definition

TYPICAL APPLICATIONS

Trench Schottky barrier rectifier are designed for high frequency miniature switched mode power supplies such as adapters, lighting and on-board DC/DC converters.

MECHANICAL DATA

Case: ITO-220AB

Molding compound meets UL 94 V-0 flammability rating

Packing code with suffix "G" means green compound (halogen-free) **Terminal:** Matte tin plated leads, solderable per JESD22-B102

Meet JESD 201 class 2 whisker test

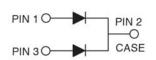
Polarity: As marked

Mounting torque: 0.56 Nm max. Weight: 1.7 g (approximately)





ITO-220AB





MAXIMUM RATINGS	AND ELE	CTRICAL	CHARACTE	RISTICS (T _A = 25°C unle	ess otherwise	noted)	
PARAMETER			SYMBOL	TSF30H45C		TSF30H60C		UNIT
Maximum repetitive peak reverse voltage		V_{RRM}	45 60		60	V		
Maximum average forward	per device		ı	30				A
rectified current	per diode		I _{F(AV)}	15				
Peak forward surge current, 8.3ms single half sine-wave superimposed on rated load per diode			I _{FSM}	170			А	
Voltage rate of change (Rated V _R)			dV/dt	10000			V/µs	
				TYP.	MAX.	TYP.	MAX.	
Instantaneous forward voltage per diode (Note1)	I _F = 5A	T _J = 25°C		0.43	-	0.45	-	V
	I _F = 7.5A			0.46	-	0.48	-	
	I _F = 15A		$V_{\rm F}$	0.53	0.61	0.55	0.70	
	I _F = 5A] VF [0.34	-	0.36	-	
	I _F = 7.5A	$T_J = 125^{\circ}C$		0.39	-	0.41	-	
	I _F = 15A			0.50	-	0.52	-	
Instantaneous reverse current per $T_J = 25^{\circ}C$ diode at rated reverse voltage $T_J = 125^{\circ}C$			25	500	15	500	μA	
		T _J = 125°C	– I _R	15	70	10	45	mA
Typical thermal resistance per diode			$R_{ heta JC}$	4.5			°C/W	
Operating junction temperature range			TJ	- 55 to +150			°C	
Storage temperature range			T _{STG}	- 55 to +150			°C	

Note 1: Pulse test with pulse width = 300µs, 1% duty cycle



ORDERING INFORMATION						
PART NO.	PACKING CODE	PACKING CODE SUFFIX	PACKAGE	PACKING		
TSF30HXXC (Note 1)	C0	G	ITO-220AB	50 / Tube		

Note 1: "XX" defines voltage from 45V (TSF30H45C) to 60V (TSF30H60C)

EXAMPLE						
PREFERRED PART NO.		PACKING CODE	PACKING CODE SUFFIX	DESCRIPTION		
TSF30H60C C0G	TSF30H60C	C0	G	Green compound		

RATINGS AND CHARACTERISTICS CURVES

(T_A = 25°C unless otherwise noted)

FIG. 1 FORWARD CURRENT DERATING CURVE

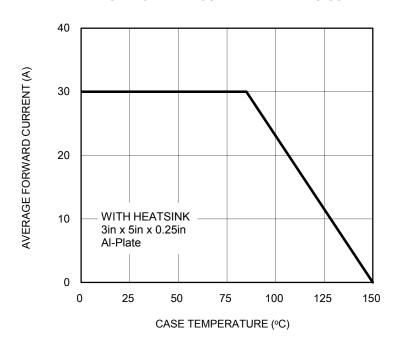


FIG. 2 TYPICAL FORWARD CHARACTERISTICS

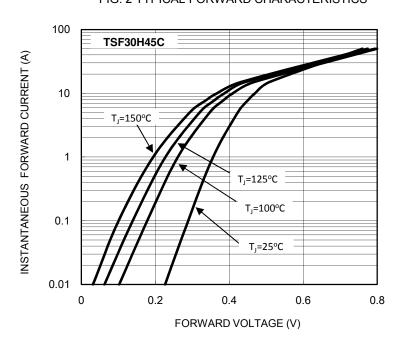


FIG. 3 TYPICAL FORWARD CHARACTERISTICS

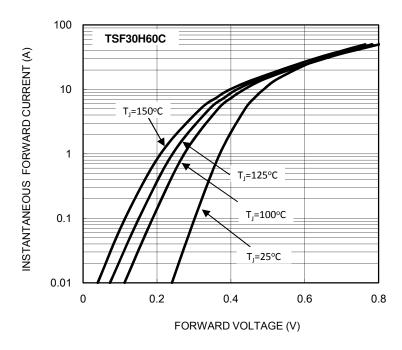


FIG. 4 TYPICAL REVERSE CHARACTERISTICS

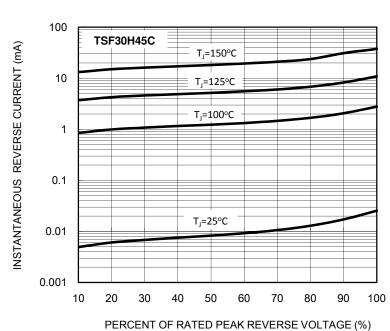




FIG. 5 TYPICAL REVERSE CHARACTERISTICS

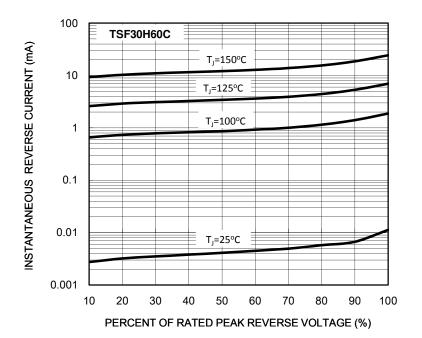
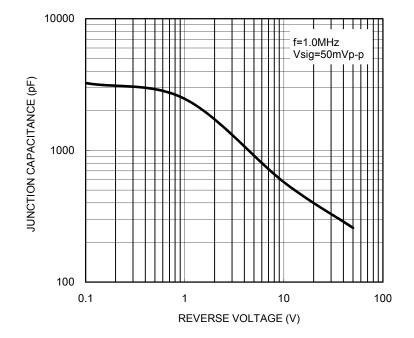
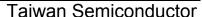


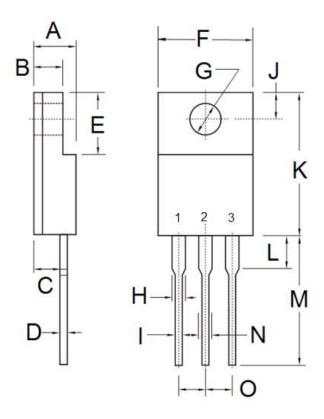
FIG. 6 TYPICAL JUNCTION CAPACITANCE







PACKAGE OUTLINE DIMENSIONS **ITO-220AB**



DIM.	Unit	(mm)	Unit (inch)		
	Min	Max	Min	Max	
Α	4.30	4.70	0.17	0.19	
В	2.50	3.16	0.10	0.12	
С	2.30	2.96	0.09	0.12	
D	0.46	0.76	0.02	0.03	
Е	6.30	6.90	0.25	0.27	
F	9.60	10.30	0.38	0.41	
G	3.00	3.40	0.12	0.13	
Н	0.95	1.45	0.04	0.06	
I	0.50	0.90	0.02	0.04	
J	2.40	3.20	0.09	0.13	
K	14.80	15.50	0.58	0.61	
L	-	4.10	-	0.16	
М	12.60	13.80	0.50	0.54	
N	-	1.80	-	0.07	
0	2.41	2.67	0.09	0.11	

MARKING DIAGRAM



P/N = Specific Device Code

= Green Compound G

YWW = Date Code

= Factory Code



Taiwan Semiconductor

Notice

Specifications of the products displayed herein are subject to change without notice. TSC or anyone on its behalf, assumes no responsibility or liability for any errors or inaccuracies.

Information contained herein is intended to provide a product description only. No license, express or implied, to any intellectual property rights is granted by this document. Except as provided in TSC's terms and conditions of sale for such products, TSC assumes no liability whatsoever, and disclaims any express or implied warranty, relating to sale and/or use of TSC products including liability or warranties relating to fitness for a particular purpose, merchantability, or infringement of any patent, copyright, or other intellectual property right.

The products shown herein are not designed for use in medical, life-saving, or life-sustaining applications. Customers using or selling these products for use in such applications do so at their own risk and agree to fully indemnify TSC for any damages resulting from such improper use or sale.

Document Number: DS_D1411060 Version: C14